# D ispersive force between dissim ilar materials: geometrical e ects

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(D ated: A pril 14, 2024)

W e calculate the C asim ir force or dispersive van der W aals force between a spherical nanoparticle and a planar substrate, both with arbitrary dielectric properties. We show that the force between a sphere and a plane can be calculated through the interacting surface plasm ons of the bodies. U sing a Spectral Representation form alism, we show that the force of a sphere m ade of a material A and a plane m ade of a material B, di er from the case when the sphere is m ade of B, and the plane is m ade of A. We found that the di erence depends on the plasm a frequency of the materials, the geom etry, and the distance of separation between sphere and plane. The di erences show the importance of the geom etry, and m ake evident the necessity of realistic descriptions of the sphere-plane system beyond the D erjaguin Approxim ation or Proxim ity Theorem Approximation.

## I. INTRODUCTION

The origin of dispersive forces like Casim ir<sup>1</sup> and van der W aals (vW ) forces<sup>2,3</sup>, between atoms and macroscopic bodies may be attributed to electrom agnetic interactions between their charge distributions induced by quantum vacuum uctuations, even when they are electrically neutral<sup>1,2,3,4</sup>. In a rst approximation, the charge distribution of neutral particles may be represented by electric dipoles. This dipole approximation was employed by London to calculate the non-retarded van der W aals interaction potential  $V_{vW}$  (z) between two identical polarizable molecules by using perturbation theory in quantum mechanics<sup>5</sup>. Later, Casim ir studied a sim pler problem<sup>1</sup>: the force between two parallel conducting plates separated by a distance z, due to the change of the zero-point energy of the classical electrom agnetic modes. He found an interaction energy per unit area,  $V_A(z) = (^2 \sim c=720) (1=z^3)$ ; where c is the speed of light. In 1956, Lifshitz<sup>3</sup> extended the theory of Casim ir to dielectric sem i-in nite slabs. A decade later, it was shown that the Lifshitz's formula could be rederived from the zero-point energy of the surface m odes of the slabs $^{6,7,8}$ .

In recent years, accurate experiments<sup>9,10,11,12,13</sup> have been performed to measure the C asim inforce which is one of the macroscopic manifestations of the uctuations of the quantum vacuum<sup>1</sup>. Most of these experiments<sup>10,11,12,13</sup> have been done using a spherical surface and a plane, instead of two parallel planes, as originally proposed C asim in<sup>1</sup> him self. The interpretation of the C asim inforce in these experiments is based on the P roximity T heorem which was developed by D erjaguin and collaborators<sup>14</sup> to estimate the force between two curved surfaces of radii R<sub>1</sub> and R<sub>2</sub>. The P roximity T heorem or D erjaguin Approximation (DA) assumes that the force on a small area of one curved surface, such that, the force per unit area is

F (z) = 2 
$$\frac{R_1R_2}{R_1 + R_2}$$
 V (z);

where V (z) is the Casim ir energy per unit area between parallel planes separated by a distance z. In the limit, when  $R_1 = R$ , and  $R_2 ! 1$ , the problem reduces to the case of a sphere of radius R and a at plane, that yields to F (z) = 2 RV (z): The force obtained using the DA is a power law function of z, where at \large" distances is proportional to z<sup>3</sup>, while at short distances F (z) / z<sup>2</sup>. This theorem is supposed to hold when z  $R_1;R_2$ , how ever, the validity of the DA has not been proved yet.

In this direction, Johansonn and Apell<sup>15</sup> studied the vW force between a sphere and a sem i-in nite slab. They calculated the electrom agnetic stress tensor associated to the electric eld correlation of the system from the G reen's function of the problem expressed in bispherical coordinates. They concluded that for sm all separations the behavior of the attractive force is consistent with the DA. How ever, one draw back of this form alism is that in bispherical coordinates the section surfaces become e planar (a point) for sm all (large) values of z, so that, arbitrary values of ratio of z=R cannot be considered to study the sphere-plane system.

C asim is showed that the energy U (z), between two parallel perfect conductor planes can be found through the change of the zero-point energy of the classical electromagnetic  $eld^1$ , like

$$U(z) = \frac{2}{2} \sum_{i}^{N} [!_{i}(z) + !_{i}(z ! 1)]; \quad (1)$$

where  $!_i(z)$  are the properm odes that satisfy the boundary conditions of the electrom agnetic eld at the planes which are separated a distance z. For realm aterials, Lifshitz obtained a formula to calculate the C asim ir force between parallel dielectric planes<sup>3</sup>. The force per unit area, according to the Lifshitz formula, is

$$f(z) = \frac{-c}{2^2} \int_{0}^{Z_{-1}} dQ Q \int_{q=0}^{Z} dk \frac{k^3 q}{q} Re \frac{1}{\tilde{\kappa}} \frac{1}{s-1} + \frac{1}{p-1};$$

with =  $[r_1 r_2 \exp (2iKz)]^{-1}$ , where  $r_j$  is the rejection amplitude coe cient of the plane j for the electrom agnetic eld with -polarization. Here, j = 1, or 2, = s or p, q = !=c, ! is the frequency, c is the speed of light, q = (Q;k) is the vacuum wavevector with projections parallel to the surface Q, and norm al to the surface k,  $\breve{k}$  = k +  $i0^{+}$  , and g is the photon occupation number of the state k .

The Lifshitz form ula depends only on the rejection coe cients of the planes and the separation between them. This rejection coeccients can be calculated for arbitrary material using the surface in pedance form alism for sem iin nite slabs<sup>16,17,18</sup> and for nite slabs using, for exam – ple, the transferm atrix form alism <sup>19,20</sup>. In addition, one observes that the Lifshitz form ula is symmetric under the change of index j = 1 ! 2, it means that the force is indistinguishable under the change of planes which is natural given the symmetry of the system.

The force between a sphere and a plane m ade of arbitrary dielectric m aterials is commonly calculated using the DA, where the C asim ir energy V (z) is found using the Lifshitz form ula. As a consequence, the force between a sphere and a plane is indistinguishable if the sphere is m ade of a m aterial A and the plane is m ade of B, or if the sphere is m ade of B and the plane is m ade of A. Furtherm ore, the DA assumes that the interaction of a sphere and a plane can be calculated as the interaction of a plane, and a set of planes, and evaluates the force by adding contributions of various distances, as if the interaction between planes were independent. However, it is well known that the Casim ir force is not an additive quantity<sup>4,21</sup>.

In this paper, we show that the geom etry of the system is important. We employ a method based on the determ ination of the proper frequencies of the system based on a spectral representation form alism<sup>22</sup>. By calculating the zero-point energy of all the interacting surface plasm ons of a sphere-plane con guration, we obtain that the force between dissimilar materials diers if the sphere is made of a material A and the plane is made of B, and vice versa. This provides an insight into the range of validity of the DA or Proximity Theorem . Also, we nd a general formula to calculate the Casim ir force di erences between arbitrary materials when the bodies are separated at least one radii of the sphere. In particular, we study the specic case of alum inum and silver. We restrict ourself to the nonretarded lim it, this means, to the case of sm all particles at sm all distances.

# II. ZERO-POINT ENERGY OF THE INTERACTING SURFACE PLASMONS

#### A. Parallelplanes

In 1968, van K am pen and collaborators<sup>6</sup> showed that the Lifshitz form ula in the nonretarded lim it is obtained from the zero-point energy of the interacting surface plasm ons of the planes. Later, G erlach<sup>7</sup> did an extension showing that also in the retarded lim it the Lifshitz form ula is obtained from the zero-point energy of the interacting surface plasm ons. A com prehensive derivation of the Lifshitz form ula using the surface m odes is also found in R ef. 4. In the case of two parallel planes, in the absence of retardation, the proper electrom agneticm odes satisfy the follow ing expression  $^{6}$ 

$$\frac{(!) + 1}{(!) 1}^{2} \exp[2kz] \quad 1 = 0$$
 (2)

for any value of 0 6 k 6 1 . The roots !  $_i$  (k) are identi ed as the oscillation frequencies of the surface plasm ons. To nd the proper m odes, it is necessary to choose a m odel for the dielectric function of the planes. To illustrate the procedure for m etallic planes, let us employ the plasm a m odel for the dielectric function, as

$$(!) = 1 \quad \frac{!_{p}^{2}}{!^{2}};$$
 (3)

with  $!_p$  the plasm a frequency. Substituting Eq. (3) in Eq. (2), we not two propermodes that, at large distances (kd 1), are given by

! 
$$\frac{!_{p}}{2}$$
 1  $\frac{1}{2} \exp[kd] \frac{1}{8} \exp[2kd]$  ; (4)

and in the limit kd ! 1, we obtain ! =  $!_p = \frac{p}{2}$  which are the frequencies of the surface plasm on of each half space. The zero-point energy per unit area will be given by

$$E_{0}(z) = \frac{1}{2} \frac{\sum_{p=1}^{Z} X}{\sum_{p=2}^{P} 2} \frac{\sum_{i=1}^{Z} X}{\sum_{i=1}^{I} k} \frac{|_{i}(k)kdk}{i}, \quad (5)$$

Now, taking the di erence of the zero-point energy when the planes are at a distance z, and when they are at in nite, we obtain the interaction energy of the system per unit area, like

$$V(z) = \frac{p}{\frac{p}{2}} \frac{16z^2}{16z^2};$$
 (6)

which depends on the energy of the surface plasm ons of the half spaces and the distance between planes.

#### B. Sphere and plane: dipolar approxim ation

Now, let us consider the case of a sphere of radius a and dielectric function  $_{\rm s}$  (!), such that, the sphere is located at a minimum distance z from the plane of dielectric function  $_{\rm p}$  (!), as shown in Fig.1. The quantum vacuum uctuations will induce a charge distribution on the sphere which also induces a charge distribution in the plane. Then, the induced lm -th multipolar moment on the sphere is given by 23

$$Q_{lm}$$
 (!) =  $_{lm}$  (!)  $V_{lm}^{vac}$  (!) +  $V_{lm}^{sub}$  (!); (7)

where  $V_{lm}^{vac}$  (!) is the eld associated to the quantum vacuum uctuations at the zero-point energy,  $V_{lm}^{sub}$  (!) is the

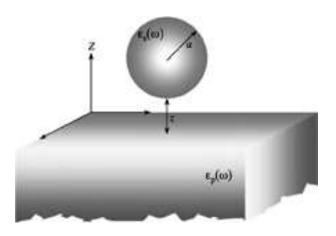


FIG.1: Schem atic m odel of the sphere-plane system .

induced eld due to the presence of the plane, and  $_{lm}$  (!) is the lm -th polarizability of the sphere.

To illustrate the procedure in detail, rst we work in the dipolar approximation, i.e., when l = 1. In section III, we will calculate the proper modes taking into account all the high-multipolar charge distributions. Using the method of images, the relation between the dipole moment on the the sphere  $p_s$  (!), and the induced dipole moment on the plane  $p_p$  (!), is

$$p_{p}(!) = \frac{1}{1 + p} (!) M \qquad \text{g}(!):$$
(8)

Here, M = (1; 1; 1) is a diagonal matrix whose elements depend on the choice of the coordinate system. From Eq. (7), one nds that the total induced dipole moment on the sphere is

$$p_{s}(!) = (!) E^{vac}(!) + T p(!); \qquad (9)$$

where the interaction between dipoles is coupled by the dipole-dipole interaction tensor

$$T = (3rr r^2 I) = r^5$$
:

Here, I is the identity matrix, and r is the vector between the centers of the sphere and the dipole-charge distribution on the plane. From Fig. 1, we nd that r =(0;0;2(z+a)), such that, M T =  $(1^{3}r 1=r^{3}; 2=r^{3})$ is a diagonal matrix. Substituting Eq.(8) in Eq.(9), one nds

$$\frac{1}{(!)}I + f_{c}(!)M \quad T_{a}(!) = G(!) \quad f(!) = E^{vac}(!);$$

(10)

where G (!) is a diagonalm atrix and

$$f_{c}(!) = [1 _{p}(!)] = [1 + _{p}(!)]$$

Multiplying Eq. (10) by  $a^3$ , one nds that each term of G (!) is dimensionless and has two parts: the left-hand side which is only associated to the material properties of

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the sphere through its polarizability  $1=~(!) = a^3 = (!)$ , and the right-hand side which is related to the geom etrical properties of the system trough a, and z. The right-hand side also depends on the material properties of the plane trough the function  $f_c(!)$ .

The eigenfrequencies of the sphere-substrate system must satisfy Eq. (10), and are independent of the exciting eld, in this case  $E^{vac}(!)$ . These frequencies can be obtained when the determ inant of the matrix in the left-side of Eq. (10) is equal to zero, i.e., detG (!) = 0. In this particular case, the eigenfrequencies can be found from the following expression

$$\frac{1}{\sim (!)} + \frac{f_{c}(!)a^{3}}{[2(z+a)]^{3}} - \frac{1}{\sim (!)} + \frac{2f_{c}(!)a^{3}}{[2(z+a)]^{3}} = 0: (11)$$

At this point, it is necessary to consider a model for the dielectric function of the sphere to nd the properm odes. A gain, we illustrate the procedure form etallic sphere and plane, using the plasm a model of Eq. (3). Moreover, we use the fact that the polarizability of the sphere, within the dipolar approxim ation and in the quasi-static lim it, is given by

$$(!) = a^{3} \frac{s(!)}{s(!) + 2}$$

In Fig. 2a, we plot, 1 = (!) and  $f_{c}(!) [2(1 + z = a)]^{3}$  as a function of ! = ! p for di erent values of z=a. The proper frequencies of the system are given when the black-solid line and the color-dotted lines intersect each other. W e observe that there are two di erent properm odes for each term on Eq. (11), giving a total of six modes for each z=a. The proper modes at the left-hand side in Fig. 2a correspond to the surface plasm on of the sphere that we denote with  $!_+$ . These modes are red-shift as the sphere approaches the plane because of the interaction between them . W hen the separation z=a increases, the modes  $!_+$ go to  $!_p = \overline{3}$ , which is the surface plasm on frequency of an isolated sphere. On the other hand, the properm odes at the right-hand side correspond to the surface plasm on of the plane and we denote them with ! . These modes are blue-shift as the sphere approaches the plane, also because of the interaction between the sphere and the plane. In this case, when the separation z=a increases, the mode ! goes to ! p= 2 which is the frequency of thesurface plasm on of the isolated plane. This behavior of the modes is clearly observed in Fig. 2b, where  $!_{+} = !_{p}$ and ! =!p are plotted as a function of z=a. This shows that the the zero-point energy of the sphere-plane system is directly associated to the interacting surface plasm ons of the sphere and the plane.

# III. EXACT CALCULATION OF THE ZERO POINT ENERGY OF A SPHERE ABOVE A PLANE

In this section we calculate the proper electrom agnetic modes of the sphere-plane system, within the non-

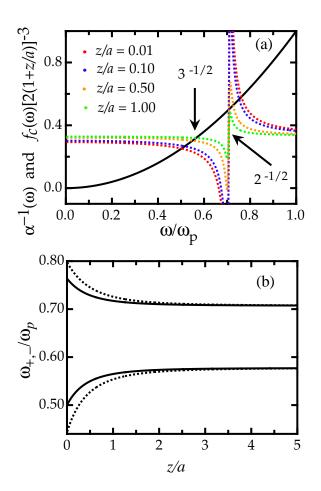


FIG. 2: (Color online) (a) P lot of  $1=\sim (!)$  in solid line and  $f_c(!)[2(1 + z=a)]^3$  as a function of  $!=!_p$  for di event values of z=a. (b) P roper m odes as a function of z=a.

retarded lim it, by including all the high-multipolar interactions. These proper modes are calculated using a Spectral Representation form alism  $^{24,25,26}$ , then, we calculate the zero-point energy using Eq. (1). The Spectral Representation (SR) form alism uses the fact that the contributions of the dielectric properties of the sphere can be separated from the contributions of its geom etrical properties. The latter allows to perform a system atic study of the sphere-plane system that may be very helpful for experimentalists. The details of the SR form alism can be found in Refs. 22 and 27, here we only explain it brie y.

We now calculate the proper modes of the system including all the high-multipolar charge distributions due to quantum vacuum uctuations. Using the method of im ages, we not from Eq. (7) that the lm-th multipolar moment on the sphere is

$$\frac{X}{1^{0}m^{\circ}} = \frac{4 \times 11^{\circ} \times m^{\circ} \times n^{\circ}}{(21+1) \times 1^{0}m^{\circ} \times (!)} + f_{c}(!) A_{1m}^{1^{0}m^{\circ}}(z) \quad Q_{1^{0}m^{\circ}}(!) = V_{1m}^{vac}(!); (12)$$

where  $A_{lm}^{1^0m^0}(z)$  is the matrix that couples the interaction between sphere and substrate<sup>23</sup>. The expression for

the interaction m atrix  $A_{lm}^{1^0m}{}^{\circ}(z)$  is given in the Appendix section, and it shows that  $A_{lm}^{1^0m}{}^{\circ}(z)$  depends only on the geom etrical properties of the system . If we have a homogeneous sphere, its polarizabilities are independent of the index m, and are given by  $^{23}$ 

$${}_{1}(!) = \frac{1[_{s}(!) 1]}{1[_{s}(!) + 1] + 1} a^{2l+1} = \frac{n_{10}}{n_{10} u(!)} a^{2l+1}; \quad (13)$$

where  $n_{10} = l=(2l+1)$ , and  $u(!) = [1 _{s}(!)]^{1}$ . Notice that in the above equation for the polarizability, the dielectric properties of the sphere are separated from its geom etrical properties. By substituting the right-hand side of the above equation, we rewrite Eq. (12) as:

X n  
u(!) 
$$_{11^{\circ} m m^{\circ}} + H_{1m}^{1^{\circ} m^{\circ}}$$
(!;z)  $\frac{Q_{1^{\circ} m^{\circ}}(!)}{(1^{\circ} a^{21^{\circ}+1})^{1=2}} = \frac{(1a^{21^{\circ}+1})^{1=2}}{4}V_{1m}^{vac}$ (!); (14)

where the lm;  $l^{0}m^{0}$ -th element of the matrix H (!;z) is

$$H_{lm}^{l^{0}m^{0}}(!;z) = n_{l^{0}0} ll^{0} m^{0}n^{0} + f_{c}(!) \frac{(a^{l+l^{0}+1})}{4} (ll^{0})^{1=2} A_{lm}^{l^{0}m^{0}}(z): (15)$$

The properm odes are given when the determ inant of the quantity between parenthesis in Eq. (14) is equal to zero, det [u(!)I + H(!;z)] = 0, that is

$$G(!;z) = \bigvee_{s}^{Y} [u(!) + n_{s}(!;z)] = 0; \quad (16)$$

where  $n_s$  (!;z) are the eigenvalues of H (!;z).

The SpectralR epresentation form alism can be applied in a very simple way. First, we have to choose a substrate to calculate the contrast factor  $f_c$  (!), with this, we construct the matrix H (!;z), and we diagonalize it to nd its eigenvalues  $n_s$  (!;z). We can repeat these steps for a set of di erent values of z. Notice that the eigenvalues of H (!;z) can be found without to do any assumption on the dielectric function of the sphere. Once we have the eigenvalues as a function of z, we have to consider an explicit form of the dielectric function of the sphere, such that, we calculate the proper electrom agneticm odes !<sub>s</sub> (z) trough the relation u (!<sub>s</sub>) =  $n_s$  (!;z).

To illustrate the procedure, we use again the plasm a model for the dielectric function of the sphere, and a plane with a constant dielectric function. In this case, the proper modes are given by

$$!_{s}(z) = !_{p}^{p} \overline{n_{s}(z)};$$
 (17)

with s = (l;m), and where the eigenvalues  $n_s(z)$ , are independent of the frequency. The zero-point energy, according with Eq. (1), is given by

$$E(z) = \frac{-!_{p}}{2} \sum_{lm}^{lm} \frac{n_{lm}(z)}{n_{lm}(z)} p_{lm}(z) \frac{1}{n_{l0}}; \quad (18)$$

where ~!  $p^{p} \overline{n_{10}} = ~! p^{p} \overline{l=(2l+1)}$ , are the energies associated to the multipolar surface plasm ons resonances of the isolated sphere. Here, l= 1;2;:::;L, where L is the largest order in the multipolar expansion. For l= 1 we have that ~!  $p^{P} \overline{n_{10}} = ~! p^{=} \overline{3}$ , that is the surface plasm on of the sphere in the dipolar approximation. When l! 1, we have that ~!  $p^{P} \overline{n_{10}} = ~! p^{=} \overline{3}$ .

Now, in the presence of the dielectric plane, the proper m odes of the isolated m etallic-sphere are m odi ed according to Eq. (15). These proper m odes are red-shift always as the sphere approaches the plane, and this shift depends on the separation z=a. We nd that the interaction energy is proportional to [I=2(1 + z=a)], where  $= 1 + 1^0 + 1$  is an integer between 3 and 2L + 1. As z=a ! 0, m ore and m ore multipolar interactions m ust be taken into account and ! 2L + 1. Finally, when the sphere is touching the plane, one would expect that L ! 1, so that also ! 1, and the energy at z = 0 is proportional to (I=2), with ! 1, it means the energy becomes also in nite.

It is possible to nd the behavior of the energy as a function of z=a for any plasm a's sphere independently of its plasm a frequency, like  $E = 2^{p}$ . Furtherm ore, the force can be also studied independently of the radius of the sphere, since E (z=a), one nds that

$$F = \frac{\partial E(z=a)}{\partial z} = \frac{\partial E(z=a)}{\partial (z=a)} \frac{\partial (z=a)}{\partial z}; \quad (19)$$

and then, we can de ne also a dimensionless force like aF = ..., p. In summary, we have shown that given the dielectric properties of the substrate the behavior of the energy and force is quite general, showing the potentiality of the Spectral Representation form alism<sup>22</sup>.

In Fig. 3, we show the dimensionless energy, E, and force aF, for a sphere and a plane both described by the plasm a model with the same plasm a frequency. We show E and aF as a function of z=a when all multipolar interactions are taken into account, as well as only dipolar, and up to quadrupolar interactions are considered. The largest multipolar moment to achieve convergence of the energy at a minimum separation of z=a = 0:1is L = 80. We observe that E and aF are power law functions of (z=a) , where depends on the order of the multipolar interaction considered. Only within the dipolar approximation, E and F a behaves like (z=a)  $^{3}$ , and  $(z=a)^4$  for any z, respectively. Let us rst analyze the system when only up to quadrupolar interactions are taken into account. In that case, the energy as well as the force, show three di erent regions: (i) at large distances, z > 5a, only dipolar interactions are im portant, (ii) when 5a > z > 2a, we found that dipolarquadrupolar interactions become important and E and F a behaves like  $(z=a)^{4}$ , and  $(z=a)^{5}$ ; while (iii) at small distances z < 2a the quadrupolar-quadrupolar interaction dom inates, and  $\vec{E}$  and  $\vec{F}$  a behaves like (z=a) <sup>5</sup>, and (z=a) <sup>6</sup>, respectively

However, as the sphere approaches the substrate the interaction between high-multipolar moments becomes

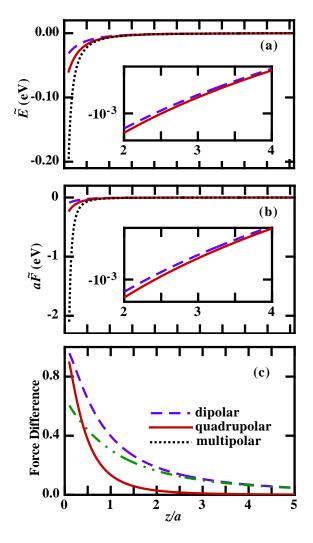


FIG. 3: (Color online) (a) Energy É, and (b) force af as a function of z=a, with L = 80 (dotted line), L = 2 (solid line), and L = 1 (dashed line). (c) Force di erence,  $j(F^{LH} F^{LW})=F^{LH}$  jusing multipolar moments LH = 80 and LW = 2 (solid line), LH = 80 and LW = 1 (dashed line), nally LH = 2 and LW = 1 (dot-dot-dashed line).

m ore and m ore im portant. The attractive force suddenly increases more than four orders of magnitude, as compare with the dipolar and quadrupolar approximations. In Fig. 3c we show the di erence of the dim ensionless force, ϳ**(Ε̂<sup>⊷∟ Η</sup>**  $F^{LW}$  )= $F^{LH}$  j as a function of the separation, with LH and LW the highest and lowest-multipolarm om ents taken into account. W e observe that at distances z > 2a the force can be obtained if up to quadrupolar interactions are considered. W e also found that for z > 7a the interaction between the sphere and the substrate can be modeled using the dipolar approximation only, like in the Casim ir and Polder model<sup>28</sup>. However, at separations sm aller than z < 2a, the quadrupolar approxim ation also fails, and it is necessary to include highmultipolar contributions. For example, at z = a the quadrupolar approxim ation gives an error of about 10%, while the dipolar approximation gives an error of about 40%. At smaller distances like z = a=2, the quadrupolar approximation gives an error of about 40%, while in the dipolar approximation the error is 70%. At z = 0.1a both approximations give an error larger than 90%. To directly compare the dipolar and quadrupolar approximations, we also plot in Fig. 3c the force di erence when LH = 2 and LW = 1. In this curve, we clearly observe that even at z = 5a there are di erences between the dipolar and quadrupolar approximations of about 5%.

The large increment of the force at small separations due to high-multipolar e ects could explain the physical origin of, for example, the large deviations observed in the de ection of atom ic beam s by m etallic surfaces<sup>29</sup>, as well as some instabilities detected in micro and nano devices. Furtherm ore, to com pare experim ental data of som e experim ents $^{12,30}$  with the DA, it has been needed to make a signi cant modi cation to the Casim ir force. In R ef. 12 the authors found a larger force than the one calculated using DA, while in Ref. 30 the authors measured a smaller one. Both groups argue that the discrepancies between theory and experim ent are due to the same e ect: the roughness of the surface. However, the discussion around this point has not sense until the DA be proven. Indeed, this am biguity on the interpretation of the measurem ents indicates that the force between a spherical particle and a planar substrate involves more complicated interactions than the simple dipole model<sup>28</sup> or the DA<sup>14</sup>. For example, such deviations might be attributed also to high-multipolar e ects, how ever, new experiments have to be perform to prove the later.

In this paper, we propose a way to elucidate experim entally two important issues to the Casim ir force: (i) the relevance of the geom etry via the surface plasm on interactions between bodies, and (ii) the relevance of the high-multipolar interactions in the sphere-plane model. In the next section, we study the case of the casim ir force between a sphere and a plane of dissim ilarm aterials that can help us to clarify these important issues.

## IV. CASIM IR FORCE BETW EEN DISSIM ILAR MATERIALS

U sing the form alism presented in the previous section, we calculate the C asim ir force for a sphere and a plane m ade of dissim ilar m aterials. To illustrate our results, we choose silver and alum inum whose dielectric function is described by the D rude m odel

$$(!) = 1 \quad \frac{!_p^2}{!(! + i=)};$$
 (20)

with plasma frequencies ~!<sub>p</sub> = 9:6 eV, and 15:8 eV, and relaxation times (!<sub>p</sub>) <sup>1</sup> = 0:0019, and 0:04, respectively. In this case, we employ the Argum ent Principle (AP) to calculate the force. The AP was rst used by van K am pen<sup>6</sup> and G erlach<sup>7</sup> to calculate the force between planes. The reader can consult Ref. 4 for a comprehensive explanation of the use of the AP within the context of C asim ir forces.

Then, employing the Argument Principle method we nd that the sum over proper modes is given as

$$E(z) = \sum_{s}^{X} \frac{\frac{1}{2}s(z)}{2} = \frac{1}{4i} \sum_{c}^{L} \frac{\frac{1}{2}G(1;z)}{\frac{1}{2}G(1;z)} \frac{1}{G(1;z)} d!;$$
(21)

where G(!;z) is de ned in Eq. (16), such that

$$E(z) = \frac{1}{4i} \int_{s}^{t} \frac{1}{0!} \log[u(!) + n_{s}(!;z)]d!: (22)$$

The closed contour C is de ned as the part along the imaginary axis plus the part along the sem icircle on the positive real axis. In the limit for a in nite sem icircle radius, the integral along the sem icircle does not depend on the separation z, therefore, it does not contribute to the force. Then, it follows that the interaction energy of Eq. (1) is given by

$$U(z) = \frac{\sum_{i=1}^{N} X^{i}}{4 i} d! \log [u(!) + n_{s}(!;z)]; \quad (23)$$

where in the last step we have perform ed a partial integration. The force is found as in Eq. (19), where we rst perform the derivate with respect to z of Eq. (23) and then the integral with respect to !.

In Fig.4, we show the calculated force for an alum inum sphere of arbitrary radius above a silver plane,  $aF_{A \models A g}$ , in solid line, and the same for a gold sphere above an alum inum plane,  $aF_{A g=A l}$ , in dashed line. We nd that the di erence is small and cannot be directly observed. Then, in Fig.4b we show the di erence of the force normalized with the average as a function of z=a, given by

$$F = 2 \frac{F_{A=B}}{F_{A=B}} \frac{F_{B=A}}{F_{B=A}}$$
; (24)

with A = A l, and B = A g. Here, we observe that the difference of force varies as a function of z=a, such that at smalldistances, (z < 0.5a) the di erence under the interchanged of materials between the sphere and the plane, is less than 3%. Then, the di erence increases with the minimum separation, and at z > a, it has alm ost reached their maximum. For these particular materials, the maximum is about 4.86%, independently of the radius of the sphere. We nd that this value of F is a consequence of the geometry of the system, as we explain below.

In the previous section, we show that for a minimum separation larger than 2a, the force can be described with quadrupolar interactions between the sphere and plane. This means that for z > 2a the force varies with the same power-law function. This conclusion can be easily deduce from Fig. 3c. We also show in section II, that the C asim ir force is given by the interaction of the surface plasm ons of the sphere and plane. In Fig. 2b, we observe that the proper modes of the system for z > a

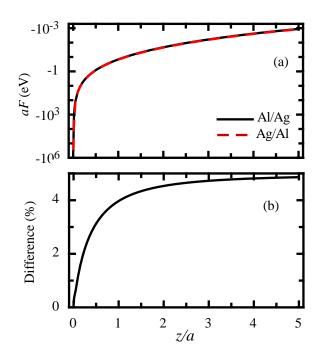


FIG. 4: (Color online) (a) Force as a function of z=a, for a sphere made of Alover an Ag plane (solid line), and for a sphere made of Ag over an Alplane (dashed line). (b) D i erence of the force between a sphere made of Alover an Ag plane, and the force for a sphere made of Ag over an Al plane.

are approximately given by  $\sim !_p = 2$  and  $\sim !_p = 3$ , when L = 1. These yield to conclude that for z > a, the force di erence is independent of z, such that

$$F' 2 \frac{\frac{\sum_{p=1}^{1} \frac{A}{p} + \sum_{p=1}^{1} \frac{B}{p}}{2} + \frac{\sum_{p=1}^{1} \frac{B}{p}}{2} + \frac{\sum_{p=1}^{1} \frac{B}{p}}{2}}{\frac{\sum_{p=1}^{1} \frac{A}{p}}{2} + \frac{\sum_{p=1}^{1} \frac{B}{p}}{2} + \frac{\sum_{p=1}^{1} \frac{B}{p}}{2}};$$

$$= 0.202 \frac{\sum_{p=1}^{1} \frac{A}{p}}{2} + \sum_{p=1}^{1} \frac{B}{p}}{2};$$
(25)

For the case of A = A l, and B = A g, we nd from Eq. (25) that F ' 4.9%, which is the calculated value shown in Fig. 4b when z > 2a. When z < a the di erence decreases as z=a also does, because m ore and m ore m ultipolar interactions become important as the sphere ap-

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proaches the plane. In the case of A l and A g, the force di erence at z=a = 0.001 is less than 0.01%, while at z=a = 0.1 the di erence is about 1.2%. In Eq. (25) we observe that as the plasm a frequency of the materials becomes more dissimilar the di erence of the force becomes larger. For example, for potassium (~!  $_{\rm p}$  = 3.8 eV) and alum inum we would nd that F ' 12.4% when z > 2a, while for gold (~!  $_{\rm p}$  = 8.55 eV) and copper (~!  $_{\rm p}$  = 10.8 eV), F ' 2.4% when z > 2a. In the other hand, the di erences become very small when z < 0.1 independently of the materials because of the high-multipolar surface plasm ons interactions.

## V. SUMMARY

In this work, we show that the Casim ir force between a sphere and a plane can be calculated through the energy obtained from their interacting surface plasmons. Our result is in agreement with the work of van Kampen and collaborators<sup>6</sup>, and G erlach<sup>7</sup> that show ed that the Casim ir force between parallelplanes can be obtained from the zero-point energy of the interacting surface plasmons of the planes. We show that the Casim ir force of a sphere made of a given material A and a plane made of a given m aterial B, is di erent from the case when the sphere is m ade of B, and the plane is m ade of A.W e obtain a form ula to estim ate the force di erence for D rudelike m aterials, when they are separated at least two radii of the sphere. We nd that the di erence depends on (i) the plasm a frequency of the materials, and (ii) the distance of separation between sphere and plane. W e also found that as the sphere approaches the plane, the force di erence becom es smaller. W e conclude that the geom etry of the system is in portant at distances larger than the radii of the sphere, where the force is dom inated by the surface plasm ons of the bodies. The energy of these surface plasm ons is equal to the plasm a frequency of the m aterials tim es a factor given by the geom etry.

### A cknow ledgm ents

We would like to thank to Carlos Villarmeal, Raul E squivel-Sirvent and Ruben G.Barrera for helpful discussions. This work has been partly nanced by CONA-CyT grant No. 36651-E and by DGAPA-UNAM grant No. N 104201.

#### APPENDIX

The tensor that couples the interaction between the sphere and the plane  $is^{23}$ 

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$$A_{lm}^{\circ} = \frac{Y_{l+1^{\circ}}^{m} (\mathbf{j'})}{\mathbf{r}^{l+1^{\circ}+1}} - \frac{(4)^{3} (l+1) + m (\mathbf{m'})! (l+1) (\mathbf{m}+\mathbf{m'})!}{(2l+1) (2l+1) (2l+2l^{\circ}+1) (l+\mathbf{m})! (l-\mathbf{m})! (l-\mathbf{m'})!}$$
(26)

where  $Y_{lm}$  (;') are the spherical harm on ics. In spherical coordinates r = (2(z+a);0;0), then, the spherical harm on ics reduce to<sup>31</sup>

$$Y_{1+1^{0}}^{m} (0; \prime) = \frac{2(1+1^{0})+1}{4}_{m}^{\#_{1=2}}$$
(27)

This means that  $m = m^{\circ}$  and multipolar moments with di erent azim uthal charge distribution are not able to couple or interact among them. This yields to

$$A_{lm}^{lm} = \frac{4}{[2(z+a)]^{l+l^0+1}} \frac{((l+l^0)!)^2}{(2l+1)(2l^0+1)(l+m)!(l-m)!(l+m)!(l^0-m)!};$$
(28)

which is a symmetric matrix.

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